Analog Multiplexers/ Demultiplexers with Injection Current Effect Control

Automotive Customized

These devices are pin compatible to standard HC405x and MC1405xB analog mux/demux devices, but feature injection current effect control. This makes them especially suited for usage in automotive applications where voltages in excess of normal logic voltage are common.

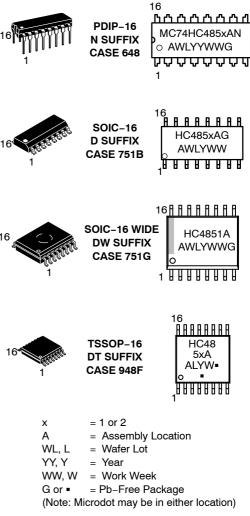
The injection current effect control allows signals at disabled analog input channels to exceed the supply voltage range without affecting the signal of the enabled analog channel. This eliminates the need for external diode/ resistor networks typically used to keep the analog channel signals within the supply voltage range.

The devices utilize low power silicon gate CMOS technology. The Channel Select and Enable inputs are compatible with standard CMOS outputs.

Features

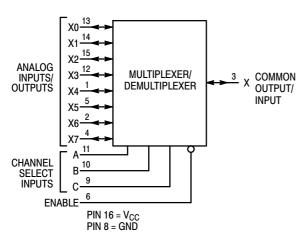
- Injection Current Cross-Coupling Less than 1mV/mA (See Figure 9)
- Pin Compatible to HC405X and MC1405XB Devices
- Power Supply Range (V_{CC} GND) = 2.0 to 6.0 V
- In Compliance With the Requirements of JEDEC Standard No. 7A
- Chip Complexity: 154 FETs or 36 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

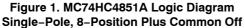




ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 12 of this data sheet.





FUNCTION TABLE - MC74HC4851A

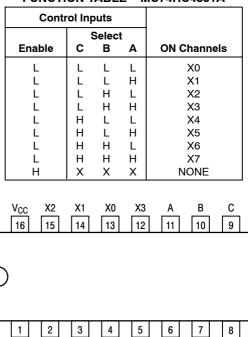


Figure 2. MC74HC4851A 16-Lead Pinout (Top View)

X5

Enable

NC

GND

Χ7

Х

X6

FUNCTION TABLE - MC74HC4852A

Control Inputs				
	Se	ect		
Enable	В	Α	ON Channels	
L	L	L	Y0	X0
L	L	н	Y1	X1
L	н	L	Y2	X2
L	н	Н	Y3	X3
Н	Х	Х	NONE	

X = Don't Care

X4

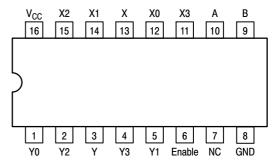
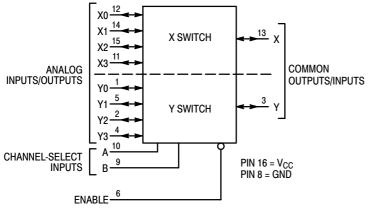
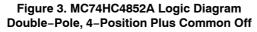


Figure 4. MC74HC4852A 16-Lead Pinout (Top View)





MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Positive DC Supply Voltage (Referenced to GND)	-0.5 to + 7.0	V
V _{in}	DC Input Voltage (Any Pin) (Referenced to GND)	-0.5 to V _{CC} + 0.5	V
I	DC Current, Into or Out of Any Pin	±25	mA
P _D	Power Dissipation in Still Air, Plastic DIP† SOIC Package† TSSOP Package†	750 500 450	mW
T _{stg}	Storage Temperature Range	-65 to + 150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds Plastic DIP, SOIC or TSSOP Package	260	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and Vout should be constrained to the range GND \leq (V_{in} or V_{out}) \leq V_{CC}.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. Plastic DIP: - 10 mW/°C from 65° to 125°C

+Derating -

SOIC Package: - 7 mW/°C from 65° to 125°C

TSSOP Package: - 6.1 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V _{CC}	Positive DC Supply Voltage (Referenced to	o GND) 2.0	6.0	V
V _{in}	DC Input Voltage (Any Pin) (Referenced to	o GND) GND	V _{CC}	V
V _{IO} *	Static or Dynamic Voltage Across Switch		1.2	V
T _A	Operating Temperature Range, All Package Types		+ 125	°C
t _r , t _f	(Channel Select or Enable Inputs) V _{CC}	= 2.0 V 0 = 4.5 V 0 = 6.0 V 0	1000 500 400	ns

*For voltage drops across switch greater than 1.2 V (switch on), excessive V_{CC} current may be drawn; i.e., the current out of the switch may contain both V_{CC} and switch input components. The reliability of the device will be unaffected unless the Maximum Ratings are exceeded.

DC CHARACTERISTICS — Digital Section (Voltages Referenced to GND) VEE = GND, Except Where Noted

		v _{cc}	Guara	nteed Lim	nit		
Symbol	Parameter	Condition	v	–55 to 25°C	≤ 85°C	≤125°C	Unit
V _{IH}	Minimum High-Level Input Voltage, Channel-Select or Enable Inputs	R _{on} = Per Spec	2.0 3.0 4.5 6.0	1.50 2.10 3.15 4.20	1.50 2.10 3.15 4.20	1.50 2.10 3.15 4.20	V
V _{IL}	Maximum Low-Level Input Voltage, Channel-Select or Enable Inputs	R _{on} = Per Spec	2.0 3.0 4.5 6.0	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	V
l _{in}	Maximum Input Leakage Current on Digital Pins (Enable/A/B/C)	V _{in} = V _{CC} or GND	6.0	± 0.1	±1.0	± 1.0	μΑ
I _{CC}	Maximum Quiescent Supply Current (per Package)	V _{in(digital)} = V _{CC} or GND V _{in(analog)} = GND	6.0	2	20	40	μΑ

DC CHARACTERISTICS — Analog Section

				Guaranteed Limit		nit	
Symbol	Parameter	Condition	v _{cc}	–55 to 25°C	≤85°C	≤125°C	Unit
R _{on}	Maximum "ON" Resistance	V_{in} = V_{IL} or $V_{IH}; V_{IS}$ = V_{CC} to GND; I_S \leq 2.0 mA	2.0 3.0 4.5 6.0	1700 1100 550 400	1750 1200 650 500	1800 1300 750 600	Ω
ΔR_{on}	Delta "ON" Resistance	$\label{eq:Vin} \begin{array}{l} V_{in} = V_{IL} \text{ or } V_{IH}; \ V_{IS} = V_{CC}/2 \\ I_S \leq 2.0 \ \text{mA} \end{array}$	2.0 3.0 4.5 6.0	300 160 80 60	400 200 100 80	500 240 120 100	Ω
I _{off}	Maximum Off-Channel Leakage Current, Any One Channel Common Channel	V _{in} = V _{CC} or GND	6.0	±0.1 ±0.1	±0.1 ±0.1	±0.1 ±0.1	μA
I _{on}	Maximum On-Channel Leakage Channel-to-Channel	$V_{in} = V_{CC}$ or GND	6.0	±0.1	±0.1	±0.1	μA

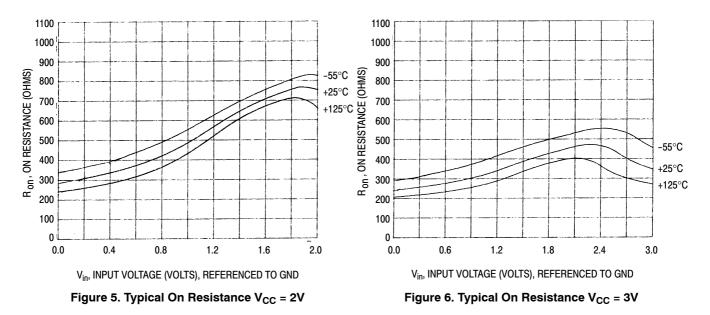
AC CHARACTERISTICS (C_L = 50 pF, Input t_r = t_f = 6 ns)

Symbol	Parameter	Vcc	–55 to 25°C	≤85°C	≤125°C	Unit
t _{PHL} ,	Maximum Propagation Delay, Analog Input to Analog Output	2.0	160	180	200	ns
t _{PLH}		3.0	80	90	100	
		4.5	40	45	50	
		6.0	30	35	40	
t _{PHL} ,	Maximum Propagation Delay, Enable or Channel-Select to Analog Output	2.0	260	280	300	ns
t _{PHZ,PZH}		3.0	160	180	200	
t _{PLH} ,		4.5	80	90	100	
t _{PLZ,PZL}		6.0	78	80	80	
C _{in}	Maximum Input Capacitance Digital Pins		10	10	10	рF
	(All Switches Off) Any Single Analog Pin		35	35	35	
	(All Switches Off) Common Analog Pin		40	40	40	
C _{PD}	Power Dissipation Capacitance Typical	5.0	20			pF

INJECTION CURRENT COUPLING SPECIFICATIONS (V_{CC} = 5V, T_A = -55^{\circ}C to +125 $^{\circ}C$)

Symbol	Parameter	Condition	Тур	Max	Unit
$V\Delta_{out}$	Maximum Shift of Output Voltage of Enabled Analog Channel	$ I_{in}^{} \star \leq 1 \text{ mA, } R_S^{} \leq 3,9 \text{ k}\Omega \\ I_{in}^{} \star \leq 10 \text{ mA, } R_S^{} \leq 3,9 \text{ k}\Omega $	0.1 1.0	1.0 5.0	mV
		$ I_{in}^{*} \leq 1 \text{ mA, } R_{S} \leq 20 \text{ k}\Omega \\ I_{in}^{*} \leq 10 \text{ mA, } R_{S} \leq 20 \text{ k}\Omega $	0.5 5.0	2.0 20	

* I_{in} = Total current injected into all disabled channels.



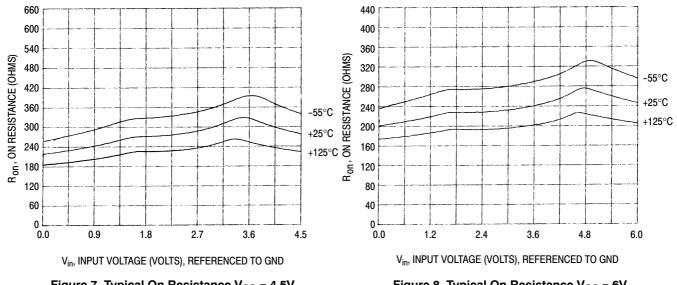


Figure 7. Typical On Resistance $V_{CC} = 4.5V$



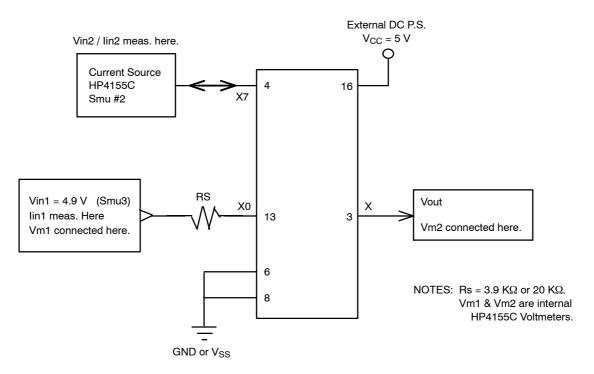


Figure 9. Injection Current Coupling Specification

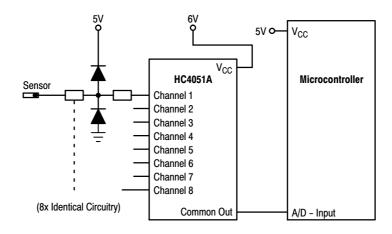


Figure 10. Actual Technology Requires 32 passive components and one extra 6V regulator to suppress injection current into a standard HC4051 multiplexer

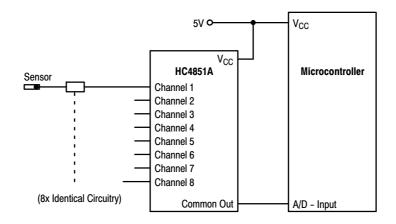
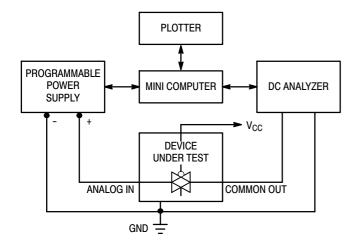
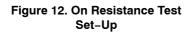


Figure 11. MC74HC4851A Solution Solution by applying the HC4851A multiplexer





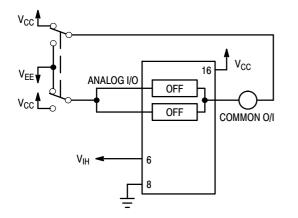


Figure 14. Maximum Off Channel Leakage Current, Common Channel, Test Set–Up

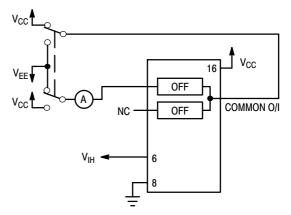


Figure 13. Maximum Off Channel Leakage Current, Any One Channel, Test Set-Up

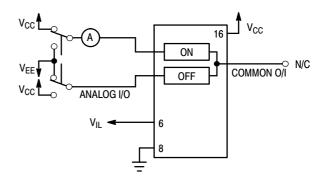
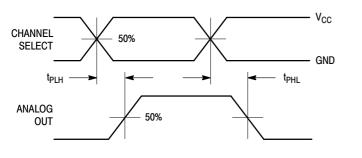
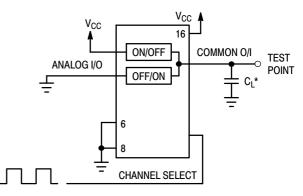


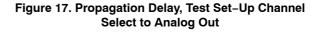
Figure 15. Maximum On Channel Leakage Current, Channel to Channel, Test Set–Up

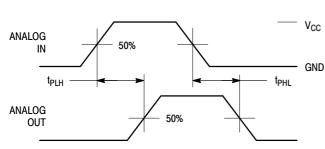


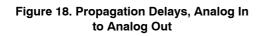


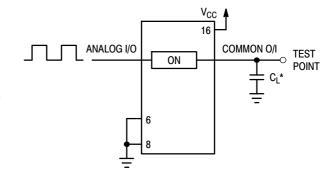


*Includes all probe and jig capacitance



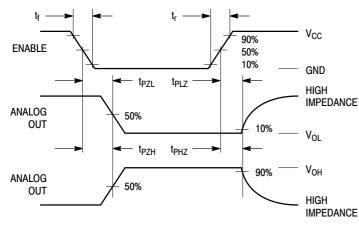




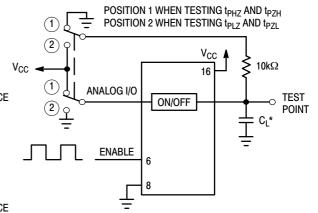


*Includes all probe and jig capacitance

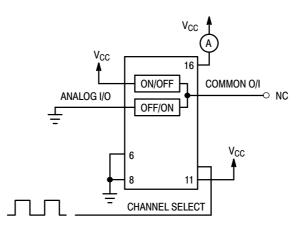
Figure 19. Propagation Delay, Test Set–Up Analog In to Analog Out

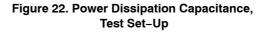












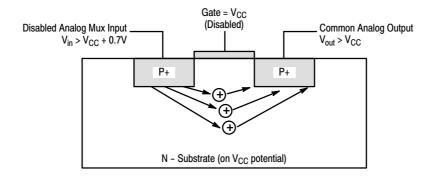


Figure 23. Diagram of Bipolar Coupling Mechanism

Appears if V_{in} exceeds V_{CC} , driving injection current into the substrate

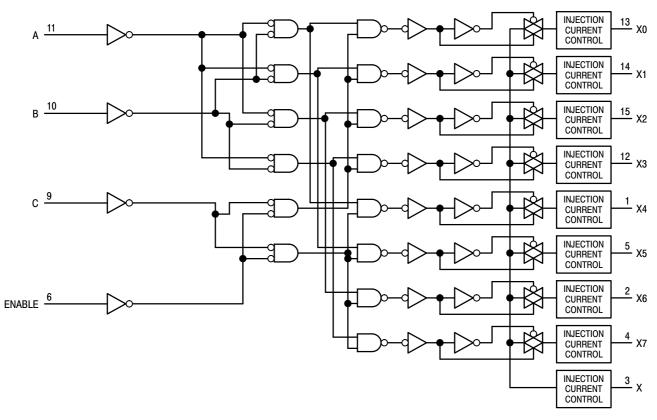
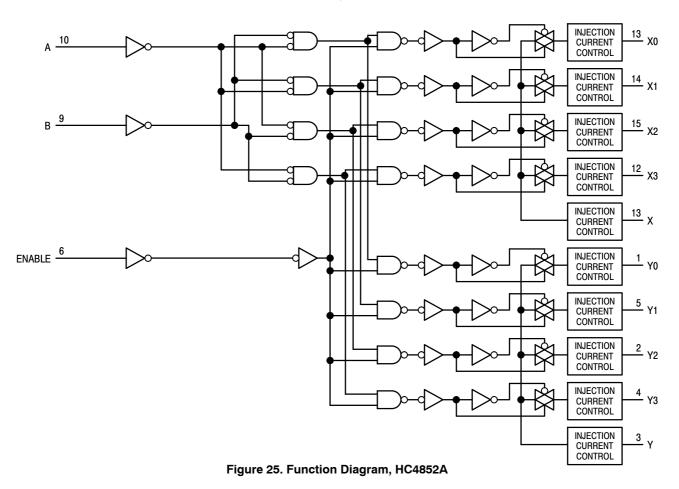


Figure 24. Function Diagram, HC4851A



ORDERING INFORMATION

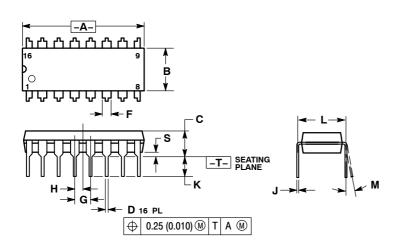
Device	Package	Shipping [†]	
MC74HC4851ANG	PDIP-16 (Pb-Free)	500 Units / Box	
MC74HC4851ADG	SOIC-16	48 Units / Rail	
MC74HC4851ADR2G	(Pb-Free)	2500 Units / Tape & Reel	
MC74HC4851ADTR2G	TSSOP-16 (Pb-Free)	2500 Units / Tape & Reel	
MC74HC4851ADWG	SOIC-16 WIDE	48 Units / Rail	
MC74HC4851ADWR2G	(Pb-Free)	1000 Units / Tape & Reel	
MC74HC4852ANG	PDIP-16 (Pb-Free)	500 Units / Box	
MC74HC4852ADG	SOIC-16	48 Units / Rail	
MC74HC4852ADR2G	(Pb-Free)	2500 Units / Tape & Reel	
MC74HC4852ADTR2G	TSSOP-16 (Pb-Free)	2500 Units / Tape & Reel	
NLV74HC4851ADR2G*	SOIC-16 (Pb-Free)	2500 Units / Tape & Reel	
NLVHC4851ADTR2G*	TSSOP-16 (Pb-Free)	2500 Units / Tape & Reel	
NLV74HC4852ADR2G*	SOIC-16 (Pb-Free)	2500 Units / Tape & Reel	
NLVHC4852ADTR2G*	TSSOP-16 (Pb-Free)	2500 Units / Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP

Capable.

PACKAGE DIMENSIONS

PDIP-16 **N SUFFIX** CASE 648-08 ISSUE T

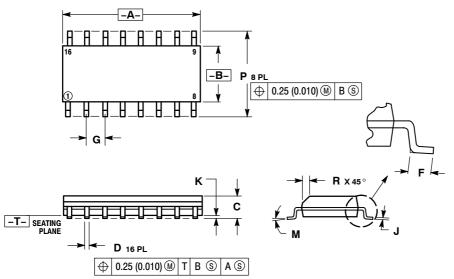


NOTES:

- 1. DIMENSIONING AND TOLERANCING PER
- 2.
- ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL. З.
- DIMENSION B DOES NOT INCLUDE MOLD FLASH. 4
- ROUNDED CORNERS OPTIONAL. 5.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.740	0.770	18.80	19.55
В	0.250	0.270	6.35	6.85
С	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100 BSC		2.54	BSC
н	0.050	BSC	1.27	BSC
J	0.008	0.015	0.21	0.38
К	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
М	0 °	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

SOIC-16 **D SUFFIX** CASE 751B-05 **ISSUE K**

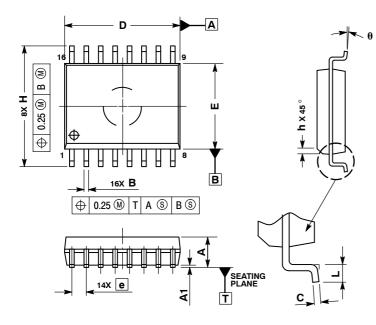


NOTES:

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION. 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE. 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27	BSC	0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
Μ	0 °	7°	0 °	7°
Р	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

SOIC-16 WIDE **DW SUFFIX** CASE 751G-03 **ISSUE C**



NOTES

1. DIMENSIONS ARE IN MILLIMETERS.

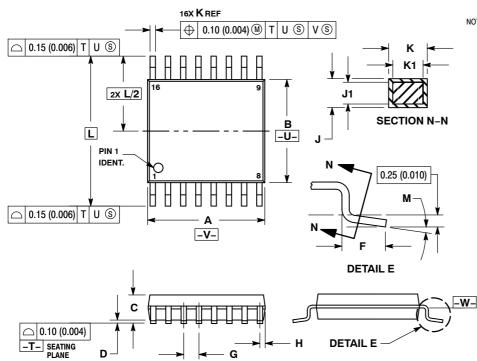
DIMENSIONS ARE IN MILLIME TENS.
INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
DIMENSIONS D AND E DO NOT INLCUDE MOLD PROTRUSION.

MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
DIMENSION B DOES NOT INCLUDE DAMBAR

PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS			
DIM	MIN	MAX		
Α	2.35	2.65		
A1	0.10 0.25			
в	0.35 0.49			
С	0.23	0.32		
D	10.15	10.45		
Е	7.40	7.60		
е	1.27	BSC		
н	10.05	10.55		
h	0.25	0.75		
L	0.50	0.90		
q	0 °	7 °		

TSSOP-16 **DT SUFFIX** CASE 948F **ISSUE B**



NOTES:

DIMENSIONING AND TOLERANCING PER ANSI DIMENSI Y14.5M, 1982. 2.

114.30%, 1992. 2. CONTROLLING DIMENSION: MILLIMETER. 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER 3.

4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE 4.

5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

7. DIMENSION ... DATUM PLANE -W-DIMENSION A AND B ARE TO BE DETERMINED AT

	MILLIMETERS		INC	HES
DIM	MIN	MAX	MIN	MAX
Α	4.90	5.10	0.193	0.200
в	4.30	4.50	0.169	0.177
С		1.20		0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65	BSC	0.026 BSC	
н	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
К	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40		0.252	
м	0 °	8 °	0 °	8 °

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